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Facile Fabrication of Boron-Doped Titania Nanopowders by Atmospheric Pressure Chemical Vapor Synthesis Route and its Photocatalytic Activity

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1. Introduction

Nowadays there is a good interest to utilize doped nanoparticles due to their application in solar cells [1], gas sensors [2], self-cleaning coatings [3, 4], magnetic, optical and electrical applications [5], environmental removing pollutants [6], and different etc. Among semiconductors, TiO₂ have achieved high attention due to high oxidation power, low cost, abundance,

Abstract

The Atmospheric Pressure Chemical Vapor Synthesis (APCVS) route is a process that can be used for the synthesis of dopednanocrystalline powders with very small crystallite sizes having a narrow particle size distribution and high purity. In this study, APCVS technique was used to prepare boron-doped titania nanopowders. The effects of temperature, borate flow rate and water flow rate on the amount of doped boron were studied. The resultant powders were characterized by inductively coupled plasma (ICP), Xray diffraction (XRD), nitrogen adsorption technique (BET), UVvisible DRS spectroscopy, scanning electron microscopy (SEM), and transmission electron microscopy (TEM). The optimum boron precursor flow rate was 80 sccm. The highest amount of doped boron was attained when water flow rate was 900 sccm. In comparison to the pristine TiO₂, the boron-doped TiO₂ nanoparticles showed blue-shift in band-gap energy of the samples.

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non toxicity, and high chemical stability [7-9]. TiO_2 has three famous structure consisted of anatase, rutile, brookite and a rather newcomer phase, TiO_2 (B) [4, 8, 10]. Between these, anatase and rutile are more applicable and the anatase phase shows a higher photocatalytic activity [7]. However, its application is limited due to wide band gap (3.2 eV and 3.0 eV for anatase and rutile), causing activity only under UV irradiation

[4, 7, 8, 11, 12]. Therefore many researchers are investigating on decreasing the band gap by metal ion implantation, doping with anions, transition metals and rare earth metals and metalloids by different methods such as sol-gel, hydrothermal, laser pyrolysis, chemical vapor deposition (CVD), chemical vapor synthesis (CVS), etc [3, 5-9, 11-17]. CVS is a facile and useful process due to its high purity, unagglomeration, high flexibility in using different kind of precursors and well controlled conditions. CVS process can be used in atmospheric pressure (APCVS), so it doesn't need expensive vacuum instruments [10, 18]. In our study, boron doped TiO₂ were synthesized via CVS method in presence of H₂O and were characterized by several analyses.

2. Experimental procedure

2.1. Nanopowder synthesis

The system configuration used in this experiment is shown in figure 1, schematically. Purified argon (Ar, purity >99.999%) carrier gas is divided to four parts. These parts are blown into bubblers containing TiCl₄ (purity >99.999%) MERCK) as TiO₂ precursor, trimethyl borate (C₃H₉BO₃) as boron precursor, purified water and other as pure Ar to fix the total flow rate. Additional oxygen (purity >99.999%) is mixed to these to ensure TiCl₄ complete reaction. The mixture is introduced to a hot-wall tubular quartz reactor with 8 cm-in diameter and 80 cm length that is heated by an external resistance furnace. The effective heated region is 20 cm in the middle of quartz reactor. The products are collected at the end of tube through two ways simultaneously, as powder through cooling by fan that particles are settled down on tube's wall and as solution through entering those particles which didn't trapped as powder with exhaust gases in a bubbler. Total flow rate and pressure are 2.1 liter per minute and 1 bar in all of processes respectively. The volume of introduced precursors and gases are controlled by needle valves and flow meters and gases pressure is controlled by pressure indicator.



Fig. 1. Schematic diagram of CVS configuration. 1) Oxygen, 2) Argon, 3) needle valve, 4) flow meter, 5)pressure indicator, 6) water, 7) trimethyl borate, 8) TiCl₄, 9) furnace, 10) quartz tube, 11) cooling fan, 12) collected particles.

Oxygen, Titanium tetrachloride (TiCl₄), and purified water were used as starting materials and introduced to the reactor in 500, 500 and 900 sccm flow rate respectively. Trimethyl borate ($C_3H_9BO_3$) was introduced as boron precursor in 20, 40, 60, 80, and 100 sccm and reactor temperature was determined 400°C.

Different reaction temperatures and its effects were studied in the next step. Reactor temperature was changed in 400, 600, 700, 800, and 900°C and precursors were in the room temperature. Oxygen, TiCl₄, water, and trimethyl borate were introduced to the reactor in 500, 500, 900 and 80 sccm flow rate respectively. These experiments were carried out to investigate the effect of boron on the photocatalytic activity of TiO₂ nanopowders and the effects of temperature, water flow rate and Boron precursor on the B-doped TiO₂ properties respectively. Scanning electron microscopy (SEM) (KYKY- EM3200- 25kV), transmission electron microscopy (TEM) (Philips- EM- 208S- 100kV), induced coupled plasma (ICP) (Perklin Emler-Optima 2000 DV), X-ray diffraction (XRD) (Stoe-Stidy-MP), nitrogen adsorption technique (BET) (QUANTACHROME- Nova 2000), and UVvisible DRS (Shimadzu- MPC-2200) were used to characterize the final products.

2.2 Measuring the amount of doped boron

The amount of boron incorporated in the Bdoped TiO_2 was measured by inductively coupled plasma (ICP). For this measurement, B-doped TiO_2 powders were dissolved in a mixture of nitric acid and fluoric acid at a molar ratio of 4:1 [7] and were heated for 24 hours.

3. Results and discussion

3.1. Effect of temperature on amount of doped boron

Table 1 shows the changes in amount of doped boron with synthesis temperature. As it's shown in table 1 the amount of boron was decreased when temperature was increased to 800°C and again was increased when temperature was 900°C. At 400 °C the powder was white, when temperature was increased to 600°C, color of powder was changed to gray and it was converted to white gradually, till to 900°C. Water flow rate and trimethyl borate flow rate were 900 and 80 sccm respectively.

 Table 1. Amount of doped boron in terms of synthesis temperature

Tomporatura (°C)	Amount of doped boron				
Temperature (C)	(ppm)				
600	224.9				
700	122.5				
800	79.4				
900	259.4				

3.1.1. XRD

XRD patterns were determined the structure of B-doped TiO₂ in different reaction temperatures and its result is shown in figure 2. The peaks for the (1 0 1), (0 0 4), (2 0 0), (1 0 5), and (2 1 1) reflections characteristic of the TiO₂ anatase phase appeared. Process temperatures ranging from 600 to 900°C produce the anatase phase. The intensity of peaks was been sharper, increasing temperature.



Fig. 2. X-ray diffraction pattern of B-doped TiO₂ under different reaction temperature. a)600°C, b)700°C, c)800°C, d)900°C.

However amorphous phase was appeared in 900°C. Therefore, it was strongly suggested the synthesis temperature should not exceed 900°C due to the appearance of the amorphous phase. It's noticeable that there is no indication of rutile peaks in the pattern even in 900°C. The diffraction peaks for boron or boron containing phases were not observed, which indicated that boron was highly dispersed on TiO₂, or XRD was not sensitive enough to detect such minor changes to TiO₂.

Also the average crystalline size was calculated by the Scherrer relationship, using XRD results:

$$d_{\rm XRD} = 0.9 \,\lambda \,/\,\beta \cos\theta \tag{1}$$

Where λ is the wavelength of the incident x-ray, θ the Bragg angle and β the full width at half

maximum (FWHM) [21]. As shown in Table 2, the crystalline sizes were increase with increasing the synthesis temperature. Vapor molecule accretion caused the crystalline size of TiO_2 to gradually increase as the temperature increased. Cluster–cluster and particle–particle collided rapidly, accelerating crystalline growth size (primary particle) and cluster (secondary particle).

3.1.2. BET

Table 2 shows the specific surface area of analyzed by the BET method. samples Agglomeration caused the surface area to decrease synthesis temperature increased. as the Furthermore, TEM observation confirmed that the prepared TiO₂ powders had an almost spherical and nonporous form. Therefore, this relationship can be expressed by a simple equation, assuming a spherical and nonporous particle:

$$d_{BET} = 6 / S_{BET} \rho_T$$
 (2)

where d_{BET} is the calculated particle size (nm), ρ_T is the TiO₂ theoretical density (3.84 g/cm³ for anatase) [17], and S_{BET} is the specific surface area (m²/g).

The results of specific surface area agree well with the TEM observation (Fig. 4), but were different from the XRD calculations. Maira and coworkers [22] claim that the specific surface area of sol-gel synthesized TiO₂ depends only on the size of crystals (primary particle) and was unaffected by aggregation. This is probably because aggregation in the sol-gel process is loose, so the N_2 gas can penetrate the gap between aggregated particles. In this study, TiO₂ aggregation occurs mostly at high temperatures (>500 °C); therefore, the particles are tightly aggregated with high surface energy. Nakaso and coworkers [23] report this phenomenon as incomplete sintering in the CVS process. Hence, the specific surface area is more related to secondary particles than primary particles in CVS process. Degree of agglomeration (N) was determined by equation (3) [21] and is shown in table 2:

$$N = d_{BET}^{3} / d_{XRD}^{3}$$
(3)

Fable 2. Results of	prepared B-dope	ed TiO ₂ at different	synthesis tem	perature
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Sample	Boron flow rate (sccm)	Water flow rate (sccm)	Temp. (°C)	Boron amount (ppm)	S _{BET} (m ² /g)	d _{XRD} (nm)	d _{BET} (nm)	Degree of Agglomeration N= d^3_{BET} / d^3_{XRD}
1	80	900	600	224	64.71	25	24	0.885
2	80	900	700	122	43.55	50	35	0.343
3	80	900	800	79	61.13	50	25	0.125
4	80	900	900	259	27.05	92	57	0.237

3.1.3. SEM

The SEM micrographs of B-doped TiO₂ nanoparticles are shown in Figure 3. From SEM analysis of the formed TiO₂ at different temperatures, the morphology difference of formed TiO₂ was observed. It was indicated that controlling temperature was critical to the control of size, size distribution and agglomeration of doped TiO₂. The dimensions of the TiO₂ nanoparticles in figure 3 (A - D) ranged from ~20 to ~100 nm and they are in spherical shapes. In addition, the nanoparticles aggregated and formed large particle blocks while increasing temperature.



Fig. 3. Boron-doped TiO₂ nanoparticles in different temperatures: A) 600°C, B)700°C, C)800°C, D)900°C.

3.1.4. TEM

TEM was applied to determine particle size, morphology, coagulation and agglomeration. As it is shown in figure 4, TEM observation confirmed that the prepared TiO₂ powders had an almost spherical and nonporous form. The size distribution of particles was narrow and nonaggregated in the lower temperatures of 600 and 700°C. In contrast, the sol–gel nanoparticle preparation method easily produced particle agglomeration after calcinations at high temperatures. The CVS process can produce a good visible-light-responsive TiO_2 without agglomeration under proper conditions. Morphological observations by TEM and XRD reveal that the large particle size of TiO_2 was mainly caused by agglomeration, not the growth of crystallite size.



Fig. 4. TEM photograph of B-doped TiO₂.3.2. Effect of boron precursor flow rate on amount of doped boron

Table 3 shows the changes in amount of doped boron with boron flow rate. As it's shown in table 3, amount of boron in TiO_2 is increased as trimethyl borate flow rate is increased to 80 sccm, and its amount is decreased when trimethyl borate flow rate is 100 sccm.

Table 3. Amount of doped boron in terms of trimethyl

 borate flow rate changes.

trimethyl borate flow	amount of doped
rate (sccm)	boron(ppm)
20	75.0
40	251.0
60	350.0
80	444.0
100	251.0

It is noteworthy that the temperature and water flow rate were 400°C and 700 sccm respectively.

3.3. Effect of water flow rate on amount of doped boron

Table 4 shows the changes in amount of doped boron with water flow rate. As it's shown in table 4, the highest amount of boron was attained when water flow rate was 900 sccm. It is noteworthy that the temperature and trimethyl borate flow rate were 400°C and 80 sccm respectively.

Table 4. Amount of doped boron in terms of water flow rate changes.

Water Flow Rate	Amount of doped		
(sccm)	Boron (ppm)		
700	474.0		
900	1361.0		
1100	1043.5		
1300	608.6		

3.4. Effect of boron on light absorption

The ultraviolet–visible light diffuse reflectance spectra (UV–Vis DRS) with a spectrophotometer was used to determine the absorption edge shift of B-doped TiO₂ nanopowder at room temperature in the wavelength range of 200–800 nm and it's results is shown in figure 5 as compared to pure TiO₂. As it is shown in this figure, B-doped TiO₂ shows more absorption in comparison to pure TiO₂ in the UV region. However a shift to UV region in the absorption edge of TiO₂ was seen when B was doped as the absorption edge is changed from 410 nm (pure TiO₂) to 380 nm for B-doped TiO₂. The UV–Vis reflectance band edge depends strongly on TiO₂ particle size, which can be attributed to the quantum size effect of semiconductors [19].

Doping boron obviously affects light absorption characteristics of TiO_2 , as shown in Figure 5. It is obvious that B-doped TiO_2 shows higher photocatalytic activity in UV region. Samples prepared in higher temperatures show higher photocatalytic activity, which could be due to the formation of anatase [7].

The absorption onset of each product was determined by a least-squares fit of the linear region of a $(Ahv)^2$ vs. hv plot (A= absorbance, h= Planck's constant, and v= frequency), as presented in Figure 6. Due to the position of their absorption threshold, band gaps of 3.2 eV for pure TiO₂ and 3.4 eV for B-doped TiO₂ were obtained [24].



Fig. 5. UV-Visible absorption spectra for prepared doped TiO_2 with different amount of boron in comparison to pure TiO_2 .



Fig. 6. Plots of $(Ahv)^2$ vs. Band energy for a) pure TiO₂ and b) B-doped TiO₂ nanoparticles.

4. Conclusion

Boron doped nanocrystalline titania powders were synthesized by a one step method using atmospheric pressure chemical vapor synthesis (APCVS). Here, trimethyl borate and TiCl₄ were used as a boron and TiO₂ feedstock, respectively. Within a certain range of the growth temperatures the TiO₂ nanoparticles were crystalline and had pure anatase structure. The particle size and crystallinity of the nanoparticles increases with increasing temperature. The nanopowders were showed extended absorption in UV region. In comparison to the pristine TiO₂, the boron-doped TiO₂ nanoparticles showed blue-shift in band-gap energy of the samples.

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سنتز ساده شیمیایی تیتانیوم دی اکسید دوپ شده با بور و فعالیت فوتوکاتالیستی آن

چکیدہ

روش سنتز بخار شیمیایی فشار اتمسفریک (APCVS) فرآیندی است که می تواند برای سنتز پودرهای نانو کریستالی doped با اندازه کریستال های بسیار کوچک که دارای توزیع اندازه ذرات محدود و بسیار خالص هستند، استفاده شوند. در این مطالعه، روش APCVS برای تهیه نانو پودرهای تیتانیوم دوپ شده با بور استفاده شده است. اثرات دما، نرخ جریان بورات و نرخ جریان آب بر مقدار بور دوپ شده مطالعه شد. پودرهای حاصل توسط پلاسمای جفتی القایی (ICP)، پراش اشعه X (XRD)، تکنیک جذب نیتروژن (BET)، طیف سنجی DRS قابل رویت UV، میکروسکوپ الکترونی روبشی (SEM)، و میکروسکوپ الکترونی عبوری (TEM) بررسی شدند. نرخ جریان ماده اولیه برون بهینه ۸۰sccm بود. بیشترین مقدار برون بور دوپ شده شده زمانی که نرخ جریان آب ۹۰۰sccm بود بدست آمد. در مقایسه با IO2 اولیه، نانو ذرات بور دوپ شده شده زمانی که نرخ جریان آب ۹۰۰sccm بود بدست آمد. در مقایسه با TiO2 اولیه، نانو ذرات